NSN 5961-01-376-2081

Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-376-2081 **Inclosure Material:** Metal **Overall Length:** 0.640 inches **Overall Diameter:** 0.390 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-double emitter **Mounting Method:** Threaded stud **Cubic Measure:** 0.305 cubic inches **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 33.0 collector to base voltage/static/emitter open and 65.0 collector to emitter voltage, dc with base short-circuited to emitter and 33.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 3.00 amperes source cutoff current **Power Rating Per Characteristic:** 21.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No